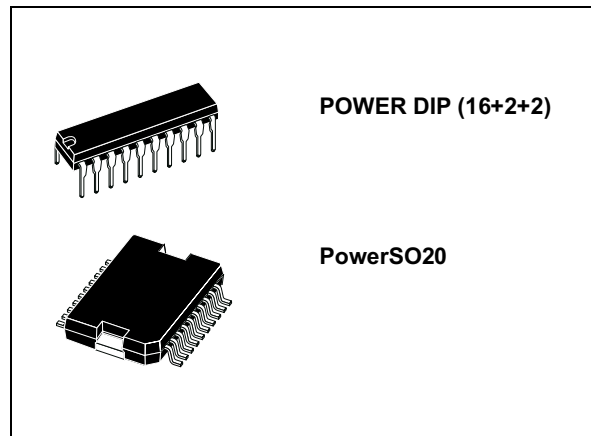


## Three phase motor driver

### Features

- Supply voltage from 7 to 52 V
- 5 A peak current
- $R_{DSon}$  0.3  $\Omega$  typ. value at 25 °C
- Cross conduction protection
- TTL compatible driver
- Operating frequency up to 150 kHz
- Thermal shutdown
- Intrinsic fast free wheeling diodes
- Input and enable function for each half bridge
- 10 V external reference available



### Description

The L6234 is a triple half bridge to drive a brushless DC motor.

It is realized in BCDmultipower technology which combines isolated DMOS power transistors with CMOS and Bipolar circuits on the same chip.

By using mixed technology it has been possible to optimize the logic circuitry and the power stage to achieve the best possible performance.

The output DMOS transistors can sustain a very high current due to the fact that the DMOS structure is not affected by the second breakdown effect, the RMS maximum current is practically limited by the dissipation capability of the package.

All the logic inputs are TTL, CMOS and  $\mu$ P compatible. Each channel is controlled by two separate logic input.

L6234 is available in 20 pin PowerDIP package (16+2+2) and in PowerSO20.

**Table 1. Device summary**

Order code	Package	Packing
L6234	PowerDIP20	Tube
L6234PD	PowerSO20	Tube
L6234PD013TR	PowerSO20	Tape and reel

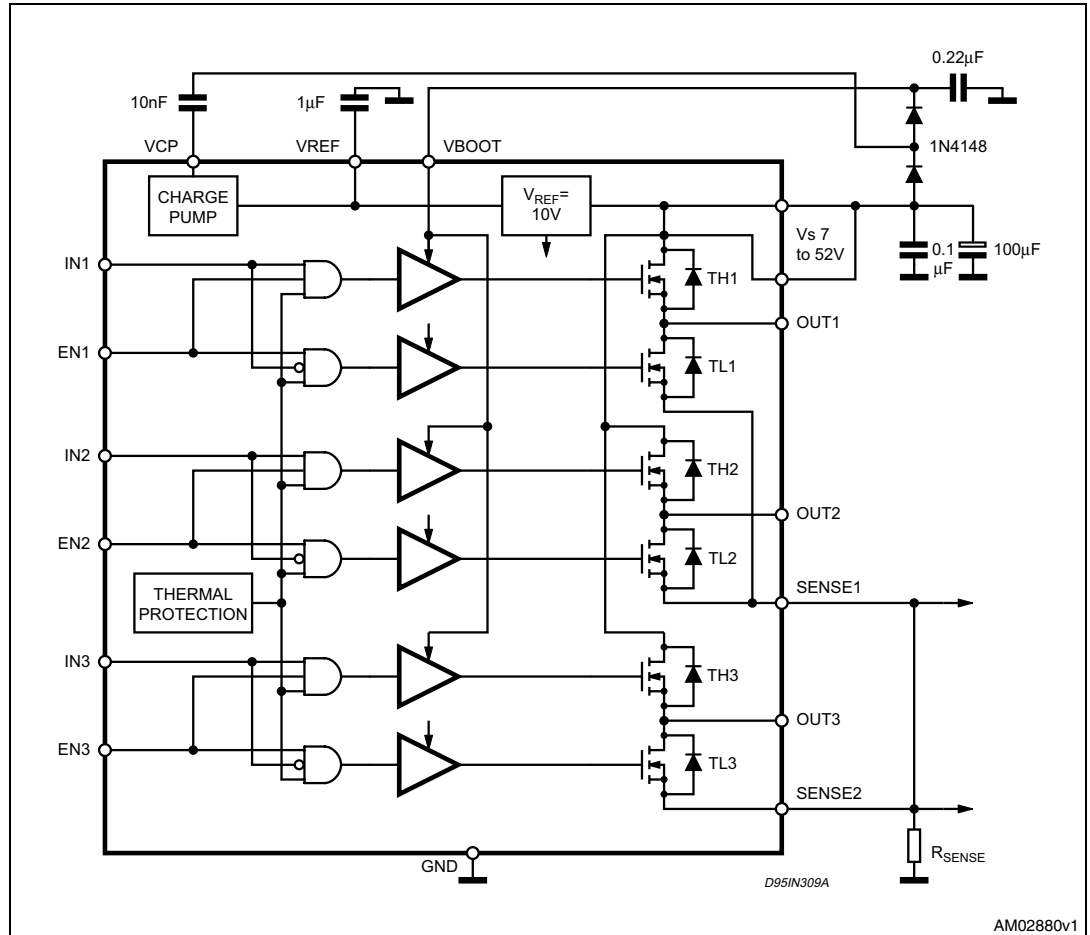
---

# Contents

1	<b>Block diagram</b> .....	3
2	<b>Pin connections</b> .....	4
3	<b>Thermal data</b> .....	5
4	<b>Maximum ratings</b> .....	6
	4.1 Recommended operating conditions .....	6
5	<b>Electrical characteristics</b> .....	7
6	<b>Circuit description</b> .....	8
7	<b>Typical characteristics</b> .....	9
8	<b>Mechanical data</b> .....	12
9	<b>Revision history</b> .....	15

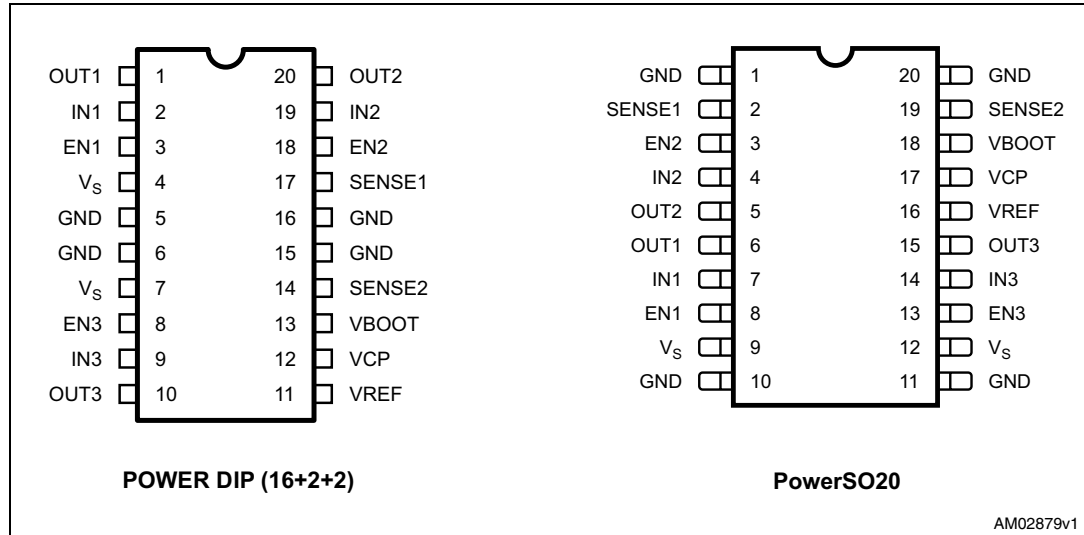
# 1 Block diagram

Figure 1. Block diagram



## 2 Pin connections

Figure 2. Pin connections



AM02879v1

Table 2. Pin functions

PowerDIP	PowerSO20	Name	Function
1 20 10	6 5 15	OUT 1 OUT 2 OUT 3	Output of the channels 1/2/3.
2 19 9	7 4 14	IN 1 IN 2 IN 3	Logic input of channels 1/2/3. A logic HIGH level (when the corresponding EN pin is HIGH) switches ON the upper DMOS Power Transistor, while a logic LOW switches ON the corresponding low side DMOS Power.
3 18 8	8 3 13	EN 1 EN 2 EN 3	Enable of the channels 1/2/3. A logic LOW level on this pin switches off both power DMOS of the related channel.
4,7	9, 12	V <sub>s</sub>	Power supply voltage.
14	19	SENSE2	A sense resistor connected to this pin provides feedback for motor current control for the bridge 3.
17	2	SENSE1	A sense resistor connected to this pin provides feedback for motor current control for the bridges 1 and 2.
11	16	VREF	Internal voltage reference. A capacitor connected from this pin to GND increases the stability of the Power DMOS drive circuit.
12	17	VCP	Bootstrap oscillator. Oscillator output for the external charge pump.
13	18	VBOOT	Overvoltage input to drive the upper DMOS
5,6 15,16	1,10 11,20	GND	Common ground terminal. In PowerDIP and SO packages these pins are used to dissipate the heat forward the PCB.

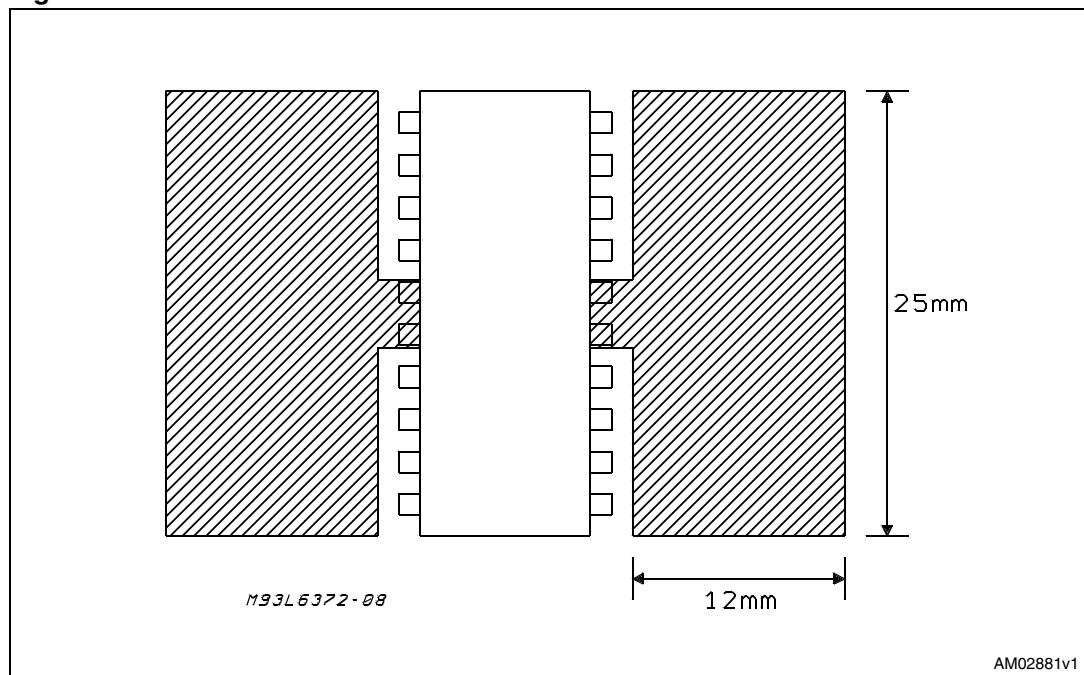
### 3 Thermal data

**Table 3. Thermal data**

Symbol	Parameter	DIP16+2+2	PowerSO20	Unit
$R_{th\ j-pin}$	Thermal resistance, junction to pin	12 <sup>(1)</sup>	–	°C/W
$R_{th\ j-amb1}$	Thermal resistance, junction to ambient	40 <sup>(2)</sup>	–	°C/W
$R_{th\ j-amb2}$	Thermal resistance, junction characteristics) to ambient	50 <sup>(3)</sup>	–	°C/W
$R_{th\ j-case}$	Thermal resistance junction-case	–	1.5	°C/W

1. The thermal resistance is referred to the thermal path from the dissipating region on the top surface of the silicon chip, to the points along the four central pins of the package, at a distance of 1.5 mm away from the stand-offs.
2. If a dissipating surface, thick at least 35 mm, and with a surface similar or bigger than the one shown in [Figure 3](#), is created making use of the printed circuit. Such heatsinking surface is considered on the bottom side of an horizontal PCB (worst case).
3. If the power dissipating pins (the four central ones), as well as the others, have a minimum thermal connection with the external world (very thin strips only) so that the dissipation takes place through still air and through the PCB itself. It is the same situation of note 2, without any heatsinking surface created on purpose on the board.

**Figure 3. Printed Heatsink**



## 4 Maximum ratings

**Table 4. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_S$	Power supply voltage	52	V
$V_{IN}, V_{EN}$	Input enable voltage	-0.3 to 7	V
$I_{peak}$	Pulsed output current <sup>(1)</sup>	5	A
$V_{SENSE}$	Sensing voltage (DC voltage)	-1 to 4	V
$V_{boot}$	Bootstrap peak voltage	62	V
$V_{OD}$	Differential output voltage (between any of the 3 OUT pins)	60	V
$f_C$	Commutation frequency	150	kHz
$V_{REF}$	Reference voltage	12	V
$P_{tot}$	Total power dissipation L6234PD, $T_A = 70^\circ\text{C}$	2.3	W
$P_{tot}$	Total power dissipation L6234, $T_A = 70^\circ\text{C}$	1.6 <sup>(2)</sup>	W
$T_{stg}, T_j$	Storage and junction temperature range	-40 to 150	$^\circ\text{C}$

1. Pulse width limited only by junction temperature and the transient thermal impedance

2. Mounted on board with minimized copper area

### 4.1 Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Value	Unit
$V_S$	Supply voltage	7 to 42	V
$V_{OD}$	Peak to peak differential voltage (between any of the 3 out pins)	52	V
$I_{out}$	DC output current powerSO20 ( $T_A = 25^\circ\text{C}$ )	4	A
	DC output current powerDIP ( $T_A = 25^\circ\text{C}$ ) with infinite heatsink	2.8	A
$V_{SENSE}$	Sensing voltage (pulsed $t_w < 300$ nsec)	-4 to 4	V
	Sensing voltage (DC)	-1 to 1	V
$T_j$	Junction temperature range	-40 to 125	$^\circ\text{C}$

## 5 Electrical characteristics

$V_S = 42\text{ V}$ ;  $T_j = 25\text{ °C}$  unless otherwise specified.

**Table 6. Electrical characteristics**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
$V_S$	Supply voltage		7		52	V
$V_{ref}$	Reference voltage			10		V
$I_S$	Quiescent supply current			6.5		mA
$T_S$	Thermal shutdown		150			°C
$T_D$	Dead time protection			300		ns
<b>Output dmos transistor</b>						
$I_{DSS}$	Leakage current				1	mA
$R_{DSon}$	ON resistance			0.3		$\Omega$
<b>Source drain diode</b>						
$V_{SD}$	Forward ON voltage	$I_{SD} = 4\text{ A}$ ; $EN = \text{LOW}$		1.2		V
$T_{RR}$	Reverse recovery time	$I_F = 4\text{ A}$		900		ns
$T_{pr}$	Forward recovery time			200		ns
<b>Logic levels</b>						
$V_{INL}, V_{ENL}$	Input LOW voltage		-0.3		0.8	V
$V_{INH}, V_{ENH}$	Input HIGH voltage		2		7	V
$I_{INL}, I_{ENL}$	Input LOW current	$V_{IN}, V_{EN} = \text{L}$			-10	$\mu\text{A}$
$I_{INH}, I_{ENH}$	Input HIGH current	$V_{IN}, V_{EN} = \text{H}$		30		$\mu\text{A}$

## 6 Circuit description

L6234 is a triple half bridge designed to drive brushless DC motors. Each half bridge has 2 power DMOS transistors with  $R_{DSon} = 0.3 \Omega$ .

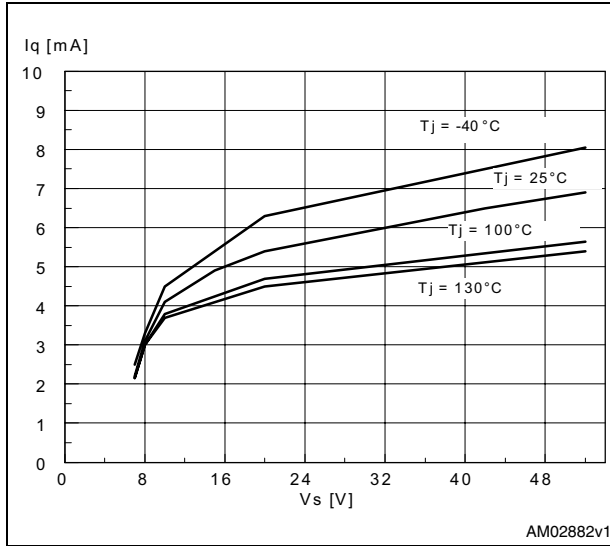
The 3 half bridges can be controlled independently by means of the 3 inputs IN1, IN2, IN3 and the 3 inputs EN1, EN2, and EN3. An external connection to the 3 common low side DMOS sources is provided to connect a sensing resistor for constant current chopping application.

The driving stage and the logic stage are designed to work from 7 V to 52 V.

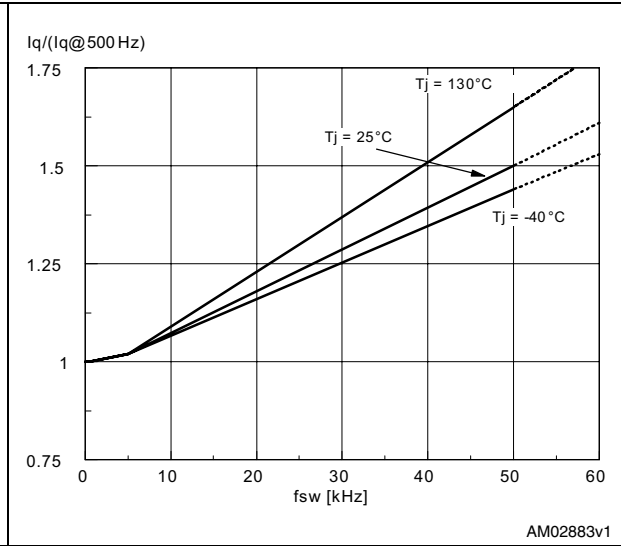


# 7 Typical characteristics

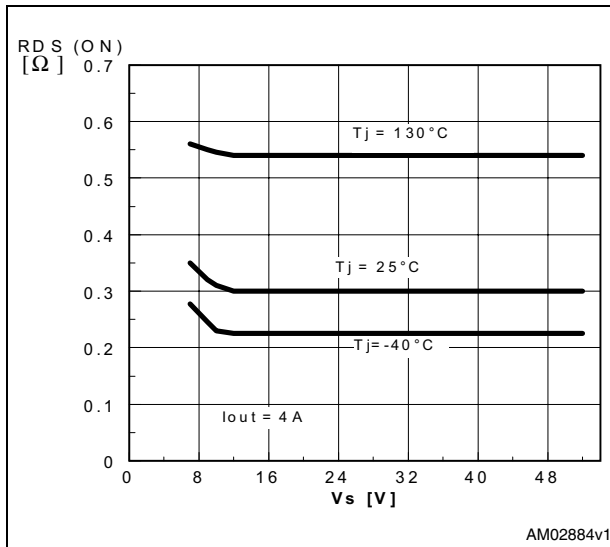
**Figure 4. Quiescent current vs. supply voltage**



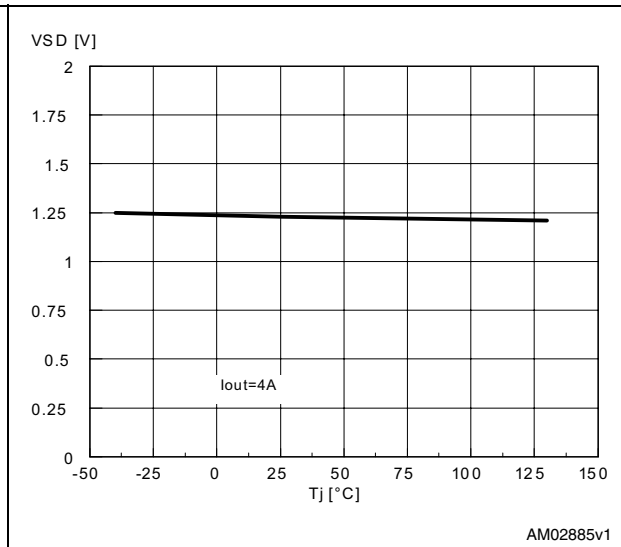
**Figure 5. Normalized quiescent current vs. switching frequency**



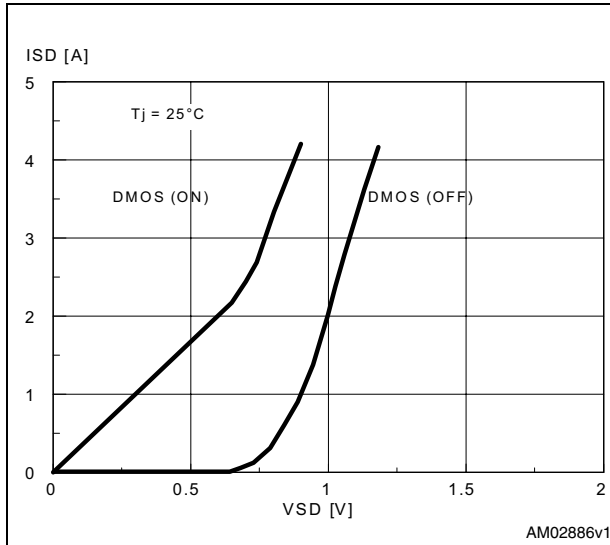
**Figure 6. Typical  $R_{DS(on)}$  vs. supply voltage**



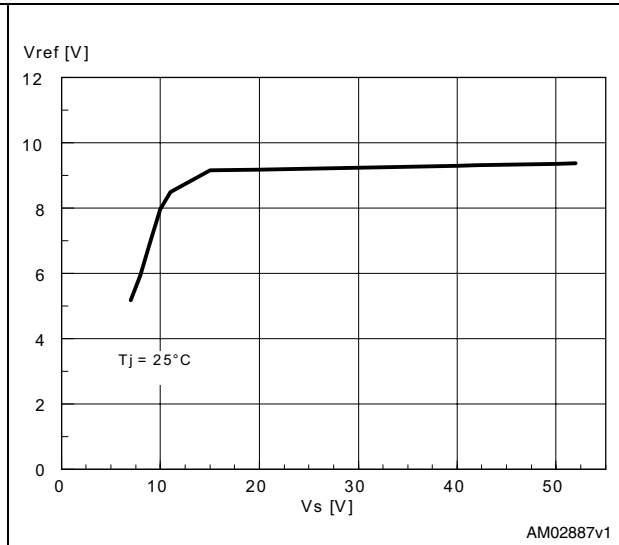
**Figure 7. Source drain forward on voltage vs. junction temperature**



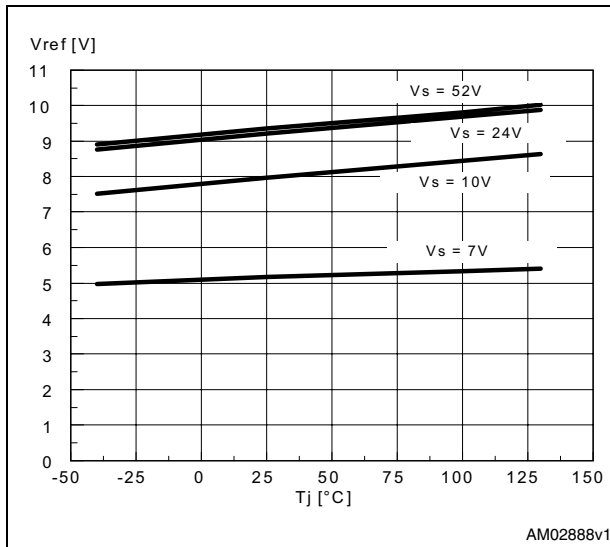
**Figure 8. Typical diode forward ON characteristics**



**Figure 9. Reference voltage vs. supply voltage**



**Figure 10. Reference voltage vs. junction temperature**



**Figure 11. PowerSO-20 transient thermal resistance**

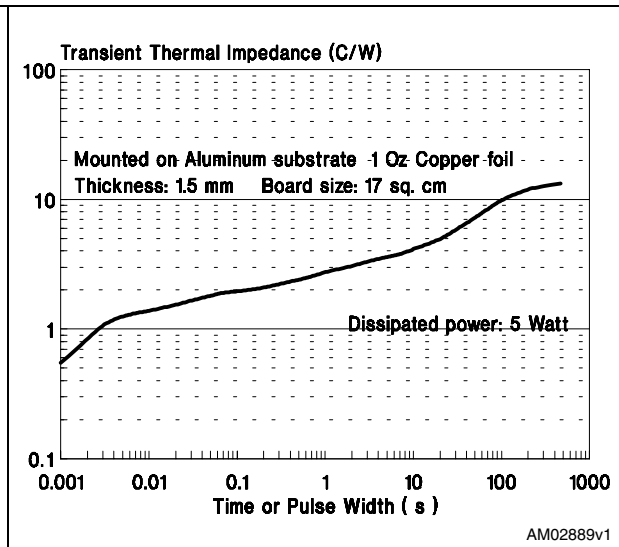


Figure 12. PowerSO-20 thermal resistance (mounted on Aluminium substrate)

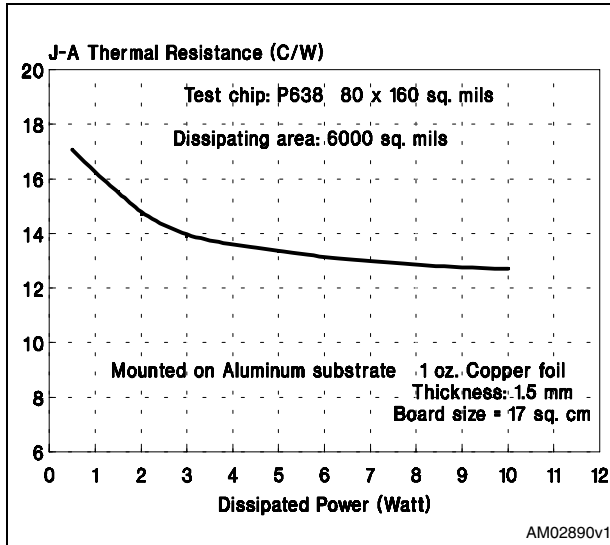


Figure 13. PowerSO-20 thermal resistance (mounted on FR4 monolayer substrate)

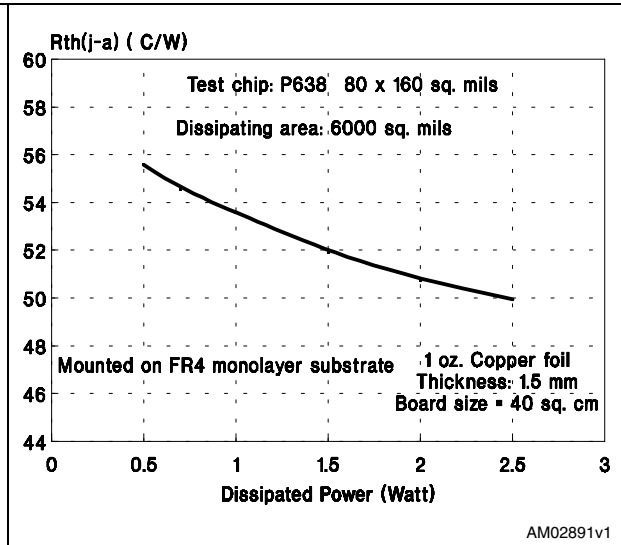


Figure 14. PowerSO-20: with external heatsink

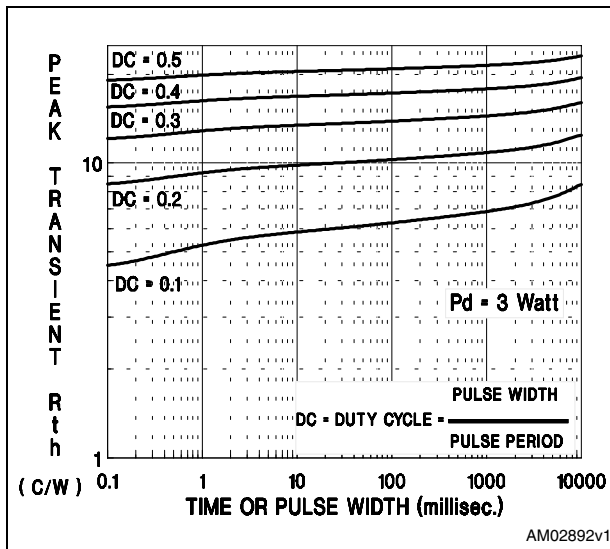
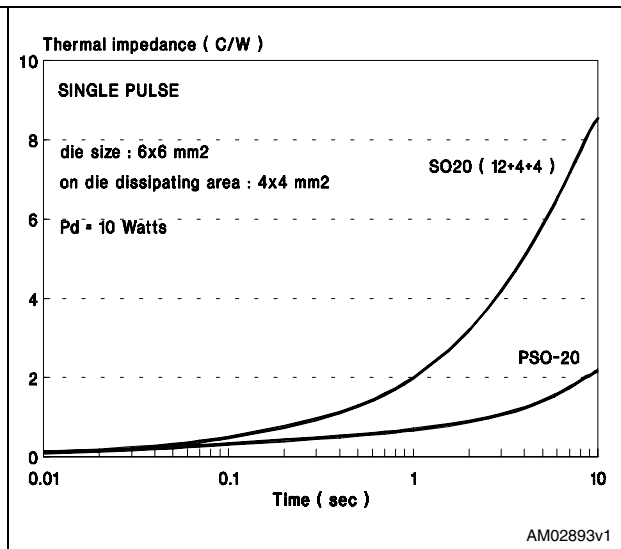


Figure 15. Thermal impedance of PowerSO-20 and standard SO20



## 8 Mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK<sup>®</sup> is an ST trademark.

**Table 7. PowerSO20 mechanical data**

Dim.	mm		
	Min.	Typ.	Max.
A			3.6
a1	0.1		0.3
a2			3.3
a3	0		0.1
b	0.4		0.53
c	0.23		0.32
D (1)	15.8		16
D1	9.4		9.8
E	13.9		14.5
e		1.27	
e3		11.43	
E1 (1)	10.9		11.1
E2			2.9
E3	5.8		6.2
G	0		0.1
H	15.5		15.9
h			1.1
L	0.8		1.1
N	8° (typ.)		
S	8° (max.)		
T		10	

Figure 16. PowerSO20 mechanical drawing

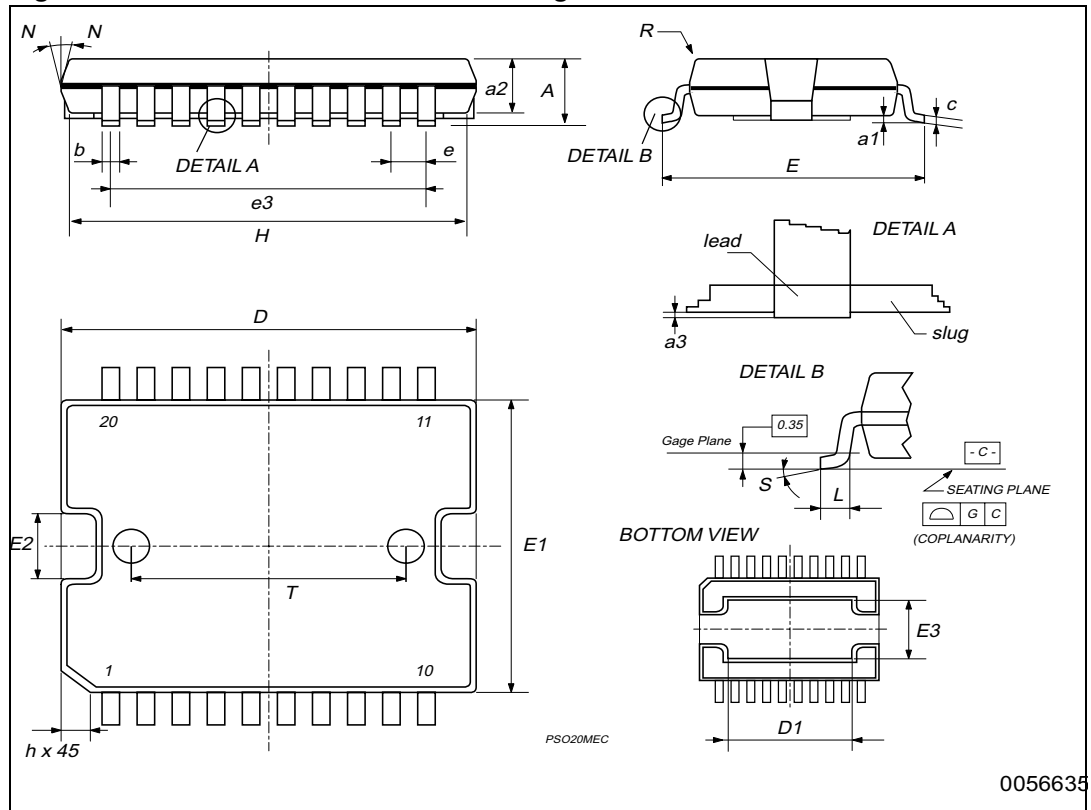
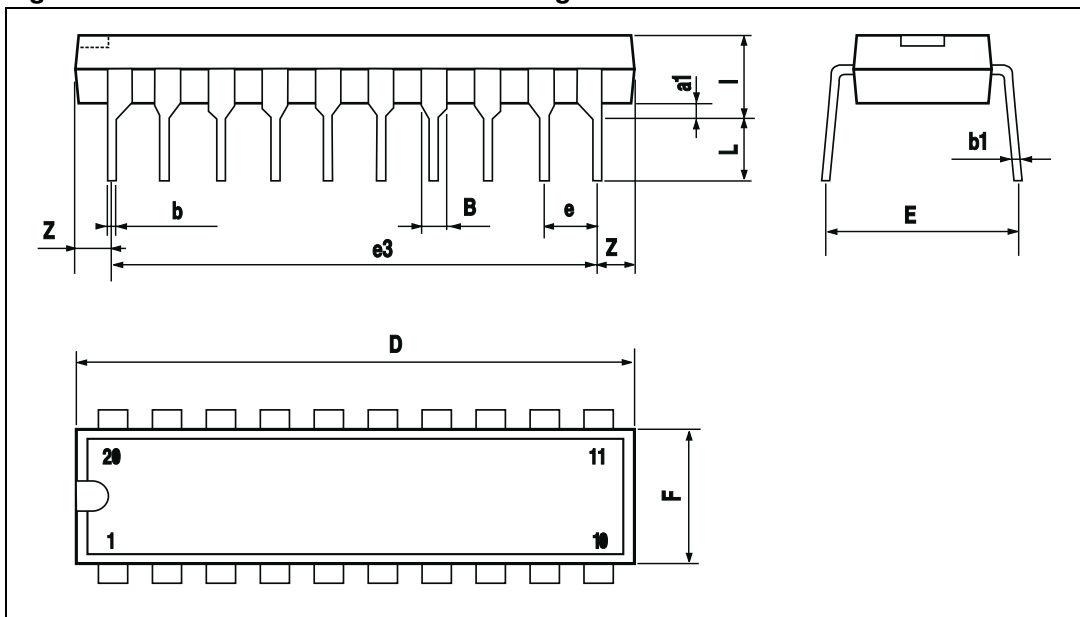


Table 8. PowerDIP20 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
a1	0.51		
B	0.85		1.40
b		0.50	
b1	0.38		0.50
D			24.80
E		8.80	
e		2.54	
e3		22.86	
F			7.10
I			5.10
L		3.30	
Z			1.27

Figure 17. PowerDIP20 mechanical drawing



## 9 Revision history

**Table 9. Document revision history**

Date	Revision	Changes
01-Aug-2003	9	
15-Nov-2011	10	Updated Features in coverpage and <a href="#">Table 4</a>

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2011 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)